Industry's first 2GB SO-DIMM for high performance server and notebook applications

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Hynix Semiconductor Inc. today announced availability of its 1Gb based DDR2 4GB Registered Dual In-line Memory Module (RDIMM) and the industry's first 2GB SO-DIMM for high performance server and notebook applications. The newly released modules will utilize Hynix's 1Gb DDR2 device manufactured on the company's leading edge 0.11-micron process technology. Hynix will plan mass production of both modules to coincide with Intel's server and notebook DDR2 chipset launch.

Hynix expects its new products will meet the various needs of high-density module in the high performance server and notebook PC market, as it allows Hynix to maintain and enhance its market leadership position in DDR2.

On the other hand, Hynix plans to focus company's resources on higher margin products such as graphics memory and consumer memory devices. The company also plans to expand and diversify its product portfolio including NAND flash memory and pseudo SRAM. In addition, Hynix aims to extend its lead in the next generation DRAM market as a company that specializes in memory business.

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